

SSC8012GN2

N-Channel Enhancement Mode MOSFET

Features

V _{DS}	V _{GS}	R _{DS(ON)} Typ.	ID
16V	±12V	12mΩ@4.5V	12A
		15mΩ@2.5V	IZA

> Description

This device is produced with high cell density DMOS trench technology, which is especially used to minimize on-state resistance. This device particularly suits low voltage applications such as portable equipment, power management and other battery powered circuits, and low in-line power dissipation are needed in a very small outline surface mount package.

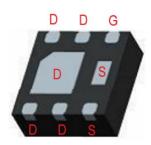
> Applications

- Load Switch
- Portable Devices
- DCDC Conversion
- Charging

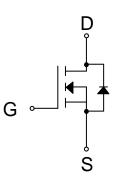
> Ordering Information

Device	Package	Shipping		
SSC8012GN2	DFN2020-6L	3000/Reel		

> Pin Configuration



DFN2020-6L (Bottom View)



Pin Configuration





> Absolute Maximum Ratings ($T_A=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Ratings	Unit		
Drain-to-Source Voltage	V _{DS}	16	V		
Gate-to-Source Voltage	V _{GS}	±12	V		
Continuous Drain Current ^d	Tc =25 ℃	1-	12	А	
Continuous Drain Current [®]	Tc=100℃	١D	7		
Pulsed Drain Current ^b	Idm	40	А		
	Tc =25 ℃	D	3.1	w	
Power Dissipation ^c	T _C =100℃	PD	1.25		
Operation junction temperature		TJ	-55~150	°C	
Storage temperature range		Tstg	-55~150		

> Thermal Resistance Ratings (T_A=25[°]C unless otherwise noted)

Parameter	Symbol Maximum		Unit	
Junction-to-Ambient Thermal Resistance ^a	R _{θJA}	40	°C/W	

Note:

- a. The value of R_{θJA} is measured with the device mounted on 1 in² FR-4 board with 2oz.copper, in a still air environment with T_A=25 °C.The value in any given application depends on the user is specific board design. The power dissipation is based on the t≤10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation P_D is based on T_{J(MAX)}=150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.
- d. The maximum current rating is package limited.



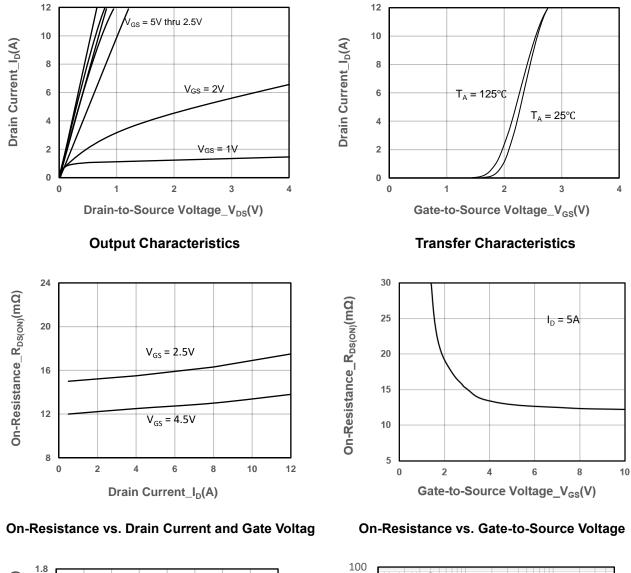


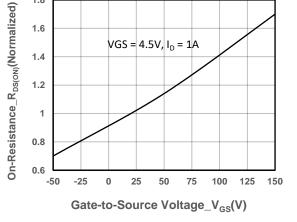
> Electrical Characteristics (T_A=25 $^{\circ}$ C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = 250uA	16			V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 uA$	0.4	0.75	1.2	V	
	R _{DS(on)}	V _{GS} = 4.5V, I _D = 6A		12	16		
Drain-Source On-Resistance		V _{GS} = 2.5V, I _D = 3A		15	20	mΩ	
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 16V, V _{GS} = 0V			1	μA	
Gate-Source Leak Current	Igss	$V_{GS} = \pm 12V, V_{DS} = 0V$			±100	nA	
Forward Voltage	V _{SD}	V _{GS} = 0V, I _S = 1A			1.3	V	
Input Capacitance	Ciss			870		pF	
Output Capacitance	Coss	$V_{DS} = 10V, V_{GS} = 0V,$		300			
Reverse Transfer Capacitance	Crss	f = 1MHz		140			
Total Gate Charge	Q_{G}			8.6		nC	
Gate to Source Charge	Q _{GS}	$V_{GS} = 4.5V, V_{DS} = 10V,$		1.9			
Gate to Drain Charge	Q_{GD}	I _D = 5A		2.2			
Turn-on Delay Time	T _{D(ON)}			6		ns	
Rise Time	Tr	$V_{GS} = 4.5V, V_{DS} = 10V,$ $R_{L} = 1.4\Omega, R_{G} = 6\Omega,$		12			
Turn-off Delay Time	T _{D(OFF)}			46			
Fall Time	T _f	I _D = 5A		22			

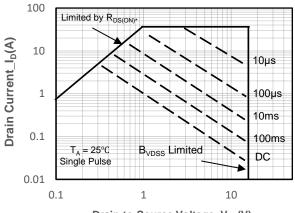


➤ Typical Performance Characteristics (T_A=25[°]C unless otherwise noted)









 $\label{eq:states} \begin{array}{l} \mbox{Drain-to-Source Voltage}_V_{DS}(V) \\ {}^*V_{GS} \mbox{>mininum } V_{GS} \mbox{ at which } R_{DS(ON)} \mbox{ is specified} \end{array}$

Safe Operating Area vs. Junction-to-Ambient

4 / 5



SSC8012GN2

0.55

0.02

0.30

2.00

2 00

0.90

0.30

0.90

0.56

0.30

0.25

0.20

0.25

0.60

0.05

0.35

2.05

2 05

1.00

0.35

1.00

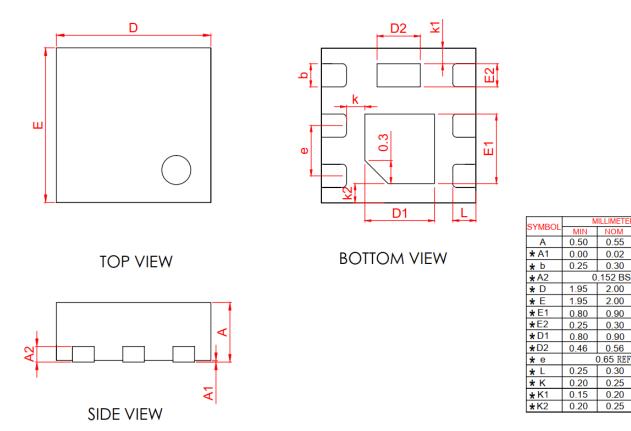
0.66

0.35 0.30

0 25

0.30

Package Information



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